

**MiniSKiiP® 2**

## 3-phase bridge inverter

### SKiiP 26AC126V1

#### Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

#### Typical Applications

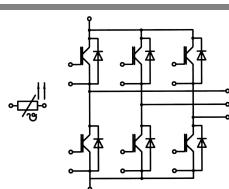
- Inverter up to 36 kVA
- Typical motor power 18,5 kW

#### Remarks

- $V_{CEsat}$ ,  $V_F$  = chip level value

| Absolute Maximum Ratings |                                    | $T_s = 25^\circ\text{C}$ , unless otherwise specified |                  |       |
|--------------------------|------------------------------------|---|------------------|-------|
| Symbol                   | Conditions                         | Values  |                  | Units |
| <b>IGBT - Inverter</b>   |                                    |   |                  |       |
| $V_{CES}$                |                                    | 1200  |                  | V     |
| $I_C$                    | $T_s = 25 (70)^\circ\text{C}$      | 88 (66)   | A                |       |
| $I_{CRM}$                | $t_p \leq 1\text{ ms}$             | 140   | A                |       |
| $V_{GES}$                |                                    | $\pm 20$  | V                |       |
| $T_j$                    |                                    | - 40 ... + 150  | $^\circ\text{C}$ |       |
| <b>Diode - Inverter</b>  |                                    |   |                  |       |
| $I_F$                    | $T_s = 25 (70)^\circ\text{C}$      | 91 (68)   | A                |       |
| $I_{FRM}$                | $t_p \leq 1\text{ ms}$             | 140   | A                |       |
| $T_j$                    |                                    | - 40 ... + 150  | $^\circ\text{C}$ |       |
| $I_{tRMS}$               | per power terminal (20 A / spring) | 100   | A                |       |
| $T_{stg}$                | $T_{op} \leq T_{stg}$              | - 40 ... + 125  | $^\circ\text{C}$ |       |
| $V_{isol}$               | AC, 1 min.                         | 2500  | V                |       |

| Characteristics           |   | $T_s = 25^\circ\text{C}$ , unless otherwise specified |            |               |
|---------------------------|---|---|------------|---------------|
| Symbol                    | Conditions  | min.  | typ.       | max.          |
| <b>IGBT - Inverter</b>    |   |   |            |               |
| $V_{CEsat}$               | $I_{Cnom} = 70\text{ A}, T_j = 25 (125)^\circ\text{C}$                                  |   | 1,7 (2)    | 2,1 (2,4)     |
| $V_{GE(th)}$              | $V_{GE} = V_{CE}, I_C = 3\text{ mA}$  | 5   | 5,8        | 6,5           |
| $V_{CE(TO)}$              | $T_j = 25 (125)^\circ\text{C}$  |   | 1 (0,9)    | 1,2 (1,1)     |
| $r_T$                     | $T_j = 25 (125)^\circ\text{C}$  |   | 10 (16)    | 13 (19)       |
| $C_{ies}$                 | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$                           |   | 4,8        | nF            |
| $C_{oes}$                 | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$                           |   | 1          | nF            |
| $C_{res}$                 | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$                           |   | 0,6        | nF            |
| $R_{th(j-s)}$             | per IGBT  |   | 0,5        | K/W           |
| $t_{d(on)}$               | under following conditions  |   | 80         | ns            |
| $t_r$                     | $V_{CC} = 600\text{ V}, V_{GE} = \pm 15\text{ V}$                                       |   | 30         | ns            |
| $t_{d(off)}$              | $I_{Cnom} = 70\text{ A}, T_j = 125^\circ\text{C}$                                       |   | 430        | ns            |
| $t_f$                     | $R_{Gon} = R_{Goff} = 9\Omega$  |   | 90         | ns            |
| $E_{on}$                  | inductive load  |   | 9          | mJ            |
| $E_{off}$                 |   |   | 7,7        | mJ            |
| <b>Diode - Inverter</b>   |   |   |            |               |
| $V_F = V_{EC}$            | $I_{Fnom} = 70\text{ A}, T_j = 25 (125)^\circ\text{C}$                                  |   | 1,5 (1,5)  | 1,7 (1,7)     |
| $V_{(TO)}$                | $T_j = 25 (125)^\circ\text{C}$  |   | 1 (0,8)    | 1,1 (0,9)     |
| $r_T$                     | $T_j = 25 (125)^\circ\text{C}$  |   | 7,1 (10)   | 8,6 (11)      |
| $R_{th(j-s)}$             | per diode   |   | 0,7        | K/W           |
| $I_{RRM}$                 | under following conditions  |   | 77         | A             |
| $Q_{rr}$                  | $I_{Fnom} = 70\text{ A}, V_R = 600\text{ V}$  |   | 18         | $\mu\text{C}$ |
| $E_{rr}$                  | $V_{GE} = 0\text{ V}, T_j = 125^\circ\text{C}$<br>$di_F/dt = 2000\text{ A}/\mu\text{s}$ |   | 7,5        | mJ            |
| <b>Temperature Sensor</b> |   |   |            |               |
| $R_{ts}$                  | 3 %, $T_r = 25 (100)^\circ\text{C}$   |   | 1000(1670) | $\Omega$      |
| <b>Mechanical Data</b>    |   |   |            |               |
| $m$                       |   | 65  |            | g             |
| $M_s$                     | Mounting torque   | 2   | 2,5        | Nm            |



AC

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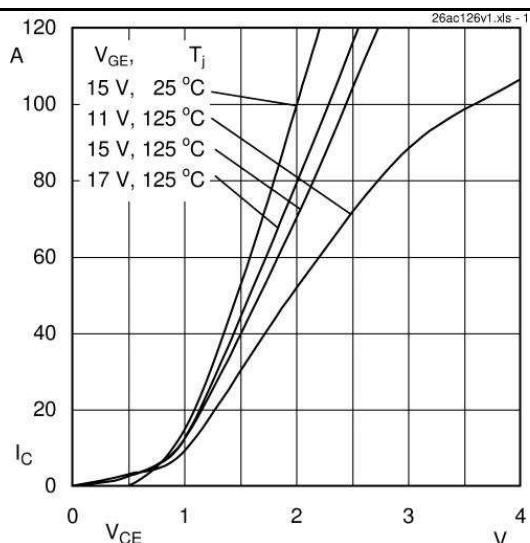


Fig. 1 Output characteristic

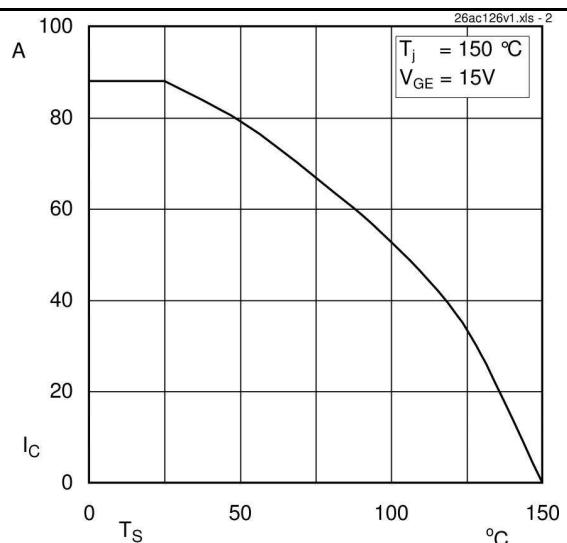


Fig. 2 Rated current vs. temperature

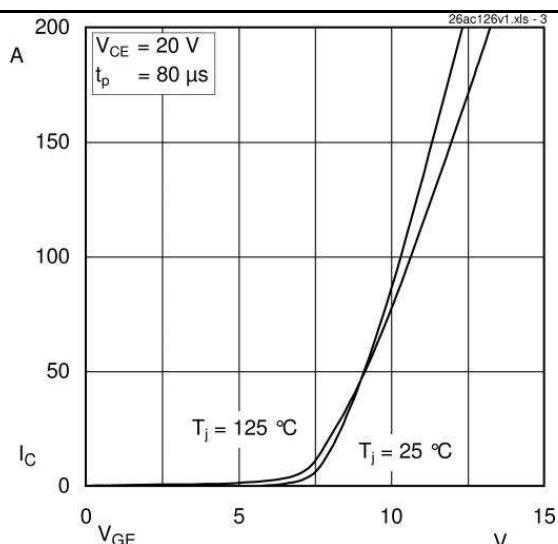


Fig. 3 Typ. transfer characteristic

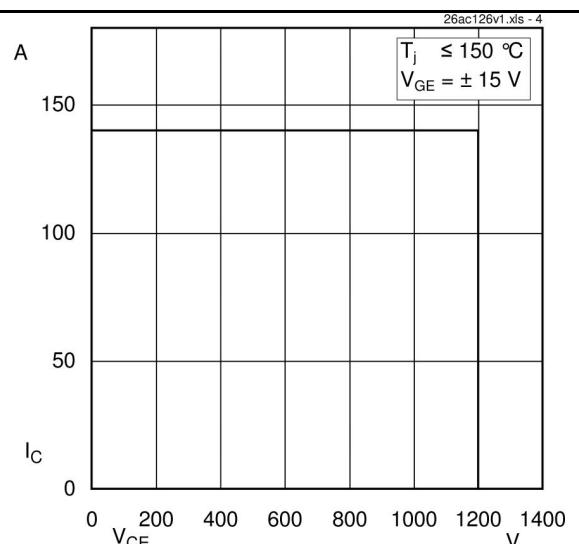


Fig. 4 Reverse bias safe operating area

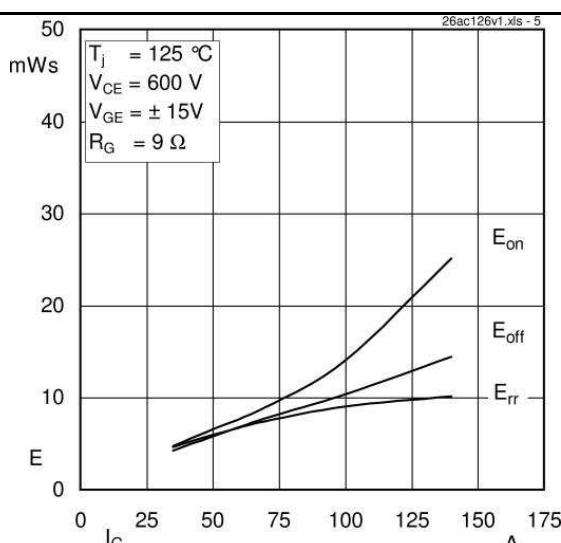


Fig. 5 Typ. Turn-on /-off energy = f ( $I_C$ )

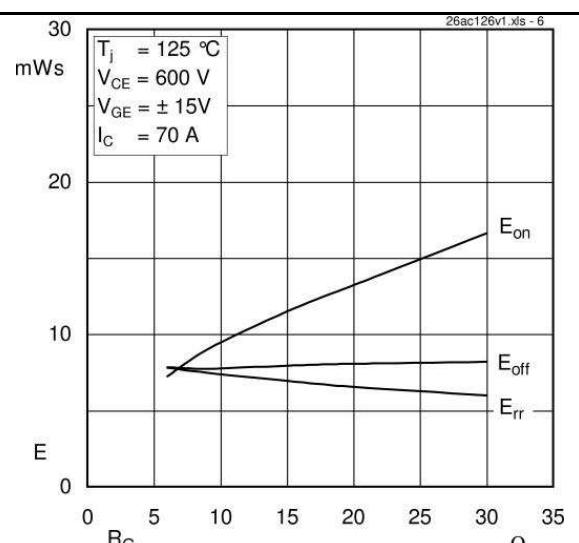


Fig. 6 Typ. Turn-on /-off energy = f ( $R_G$ )

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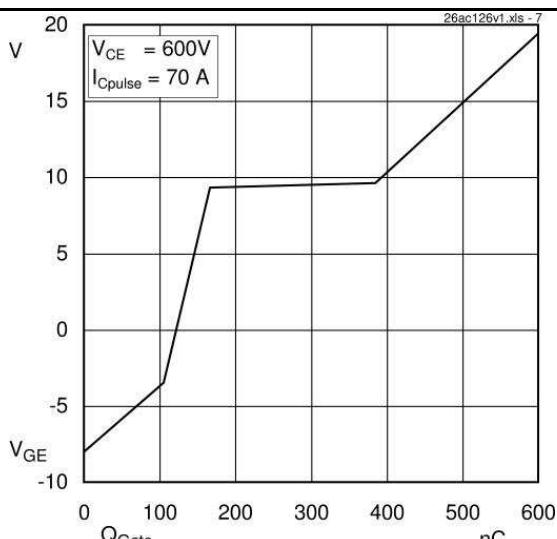


Fig. 7 Typ. gate charge characteristic

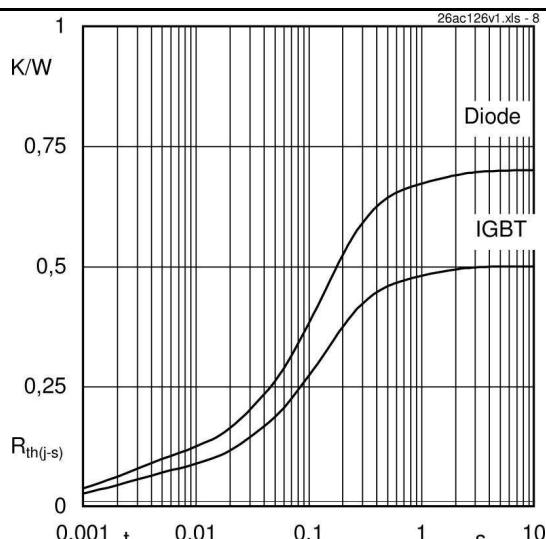


Fig. 8 Typ. thermal impedance

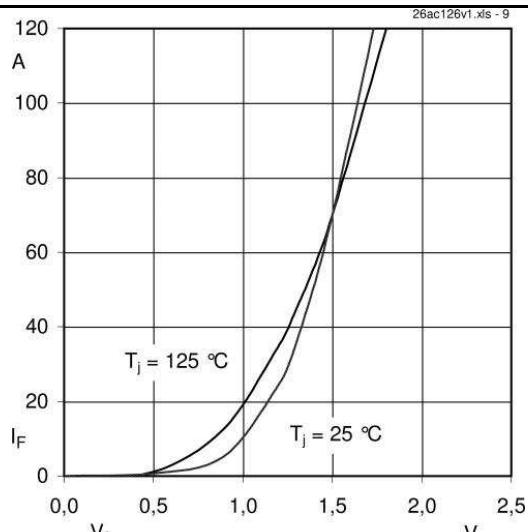
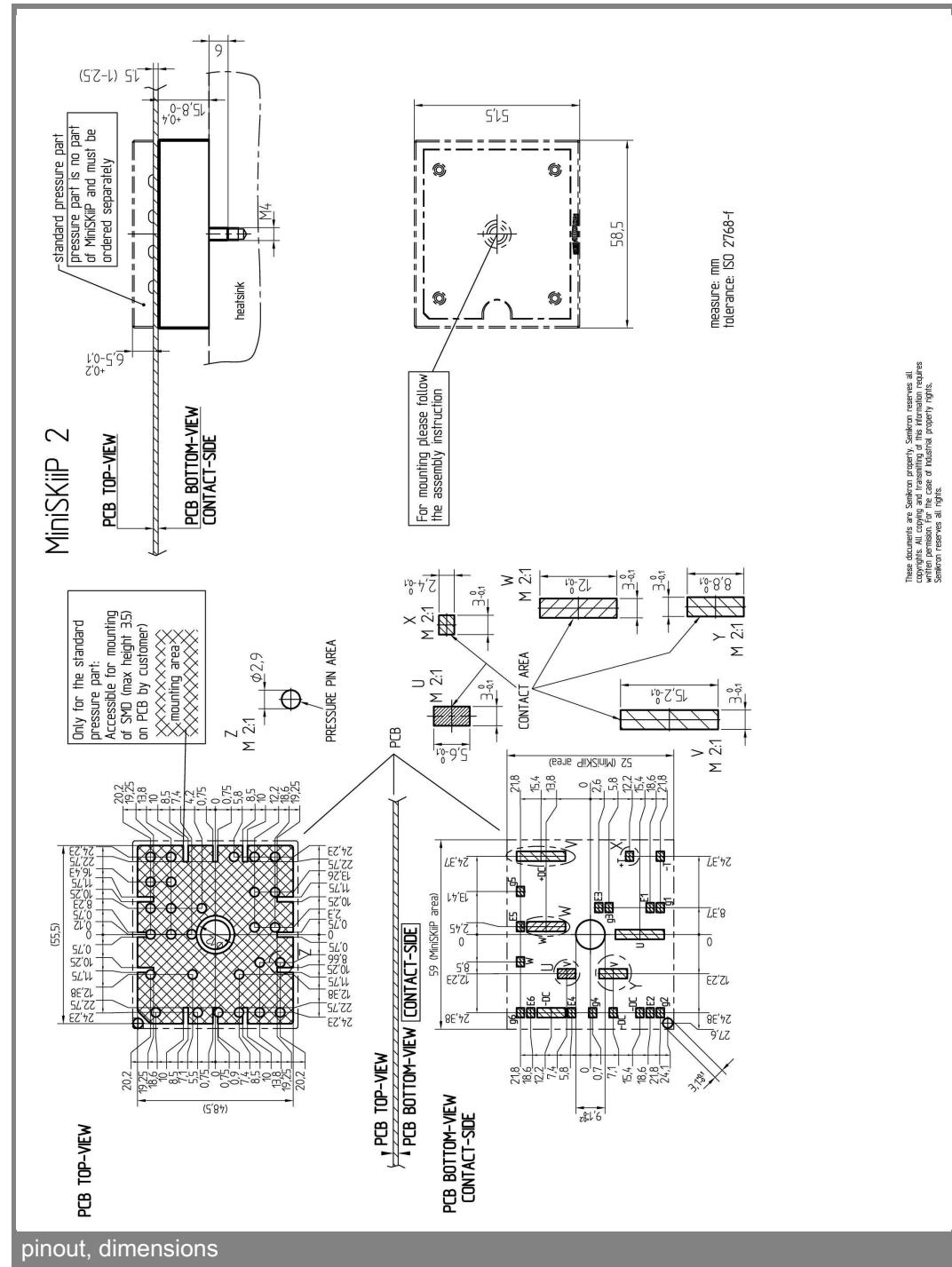
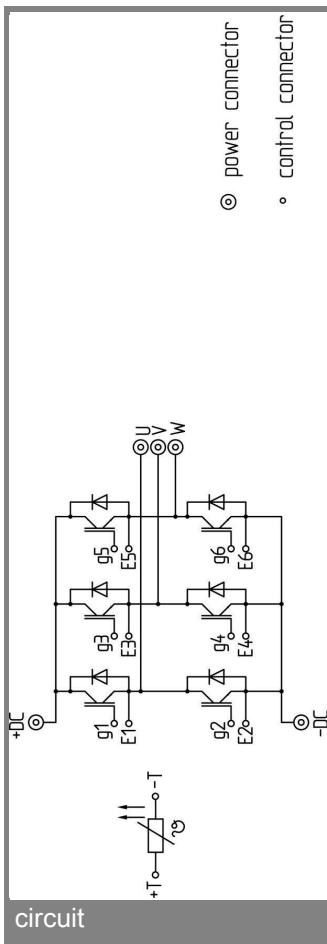


Fig. 9 Typ. freewheeling diode forward characteristic



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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